

Data sheet acquired from Harris Semiconductor

CD74AC153, **CD74ACT153**

September 1998

Dual 4-Input Multiplexer

Features

- · Buffered Inputs
- Typical Propagation Delay
 - 6.3ns at $V_{CC} = 5V$, $T_A = 25^{\circ}C$, $C_L = 50pF$
- Exceeds 2kV ESD Protection MIL-STD-883, Method
- SCR-Latchup-Resistant CMOS Process and Circuit
- Speed of Bipolar FAST™/AS/S with Significantly **Reduced Power Consumption**
- Balanced Propagation Delays
- AC Types Feature 1.5V to 5.5V Operation and Balanced Noise Immunity at 30% of the Supply
- ±24mA Output Drive Current
 - Fanout to 15 FAST™ ICs
 - Drives 50Ω Transmission Lines

Description

The CD74AC153 and CD74ACT153 are dual 4-input multiplexers that utilize the Harris Advanced CMOS Logic technology. One of the four sources for each section is selected by the common Select inputs, S0 and S1. When the Enable inputs $(\overline{1E}, \overline{2E})$ are HIGH, the outputs are in the low state.

Ordering Information

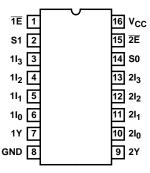
PART NUMBER	TEMP. RANGE (^o C)	PACKAGE	PKG. NO.
CD74AC153E	0 to 70 ^o C, -40 to 85, -55 to 125	16 Ld PDIP	E16.3
CD74ACT153E	0 to 70°C, -40 to 85, -55 to 125	16 Ld PDIP	E16.3
CD74AC153M96	0 to 70°C, -40 to 85, -55 to 125	16 Ld SOIC	M16.15
CD74ACT153M	0 to 70°C, -40 to 85, -55 to 125	16 Ld SOIC	M16.15

NOTES:

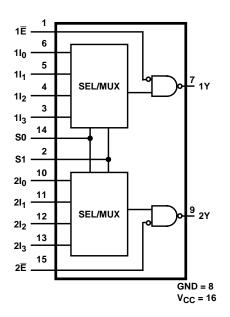
- 1. When ordering, use the entire part number. Add the suffix 96 to obtain the variant in the tape and reel.
- 2. Wafer and die for this part number is available which meets all electrical specifications. Please contact your local sales office or Harris customer service for ordering information.

Pinout

CD74AC153, CD74ACT153 (PDIP, SOIC) **TOP VIEW**



Functional Diagram



TRUTH TABLE

SELECT	INPUTS		DATA I	ENABLE INPUTS	OUTPUT		
S 1	S0	nl ₀	nl ₁	nl ₂	nl ₃	nE	nY
Х	X	Х	Х	Х	Х	Н	L
L	L	L	Х	Х	Х	L	L
L	L	Н	Х	Х	Х	L	Н
L	Н	Х	L	Х	Х	L	L
L	Н	Х	Н	Х	Х	L	Н
Н	L	Х	Х	L	Х	L	L
Н	L	Х	Х	Н	Х	L	Н
Н	Н	Х	Х	Х	L	L	L
Н	Н	Х	Х	Х	Н	L	Н

Select inputs S1 and S0 are common to both sections. H = High Level, L = Low Level, X = Don't Care, Z = High Impedance.

Absolute Maximum Ratings

DC Supply Voltage, V _{CC} 0.5V to 6V
DC Input Diode Current, I _{IK}
For $V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$
DC Output Diode Current, I _{OK}
For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$
DC Output Source or Sink Current per Output Pin, IO
For $V_O > -0.5V$ or $V_O < V_{CC} + 0.5V$
DC V _{CC} or Ground Current, I _{CC or} I _{GND} (Note 3) ±100mA

Thermal Information

Thermal Resistance (Typical, Note 5) θ _{JA} (^o C/	W)
PDIP Package)
SOIC Package	0
Maximum Junction Temperature (Plastic Package) 1	50°C
Maximum Storage Temperature Range65°C to 1	
Maximum Lead Temperature (Soldering 10s)3	00°C

Operating Conditions

Temperature Range, T _A
Supply Voltage Range, V _{CC} (Note 4)
AC Types1.5V to 5.5V
ACT Types
DC Input or Output Voltage, V _I , V _O 0V to V _{CC}
Input Rise and Fall Slew Rate, dt/dv
AC Types, 1.5V to 3V 50ns (Max)
AC Types, 3.6V to 5.5V
ACT Types, 4.5V to 5.5V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTES:

- 3. For up to 4 outputs per device, add $\pm 25 \text{mA}$ for each additional output.
- 4. Unless otherwise specified, all voltages are referenced to ground.
- 5. θ_{JA} is measured with the component mounted on an evaluation PC board in free air.

DC Electrical Specifications

		1	ST ITIONS	v _{cc}	25°C		-40°C TO -55°C 25°C 85°C 125°				
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
AC TYPES											
High Level Input Voltage	V _{IH}	-	-	1.5	1.2	-	1.2	-	1.2	-	V
				3	2.1	-	2.1	-	2.1	-	V
				5.5	3.85	-	3.85	-	3.85	-	V
Low Level Input Voltage	V _{IL}	-	-	1.5	-	0.3	-	0.3	-	0.3	V
				3	-	0.9	-	0.9	-	0.9	V
				5.5	-	1.65	-	1.65	-	1.65	V
High Level Output Voltage	VoH	V _{IH} or V _{IL}	-0.05	1.5	1.4	-	1.4	-	1.4	-	V
			-0.05	3	2.9	-	2.9	-	2.9	-	V
			-0.05	4.5	4.4	-	4.4	-	4.4	-	V
			-4	3	2.58	-	2.48	-	2.4	-	V
			-24	4.5	3.94	-	3.8	-	3.7	-	V
			-75 (Note 6, 7)	5.5	-	-	3.85	-	-	-	V
			-50 (Note 6, 7)	5.5	-	-	-	-	3.85	-	V

DC Electrical Specifications (Continued)

		TEST CONDITIONS		v _{cc}	25	o°C		C TO °C	-55°C TO 125°C		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
Low Level Output Voltage	V_{OL}	V _{IH} or V _{IL}	0.05	1.5	-	0.1	-	0.1	-	0.1	V
			0.05	3	-	0.1	-	0.1	-	0.1	V
			0.05	4.5	-	0.1	-	0.1	-	0.1	V
			12	3	-	0.36	-	0.44	-	0.5	V
			24	4.5	-	0.36	-	0.44	-	0.5	V
			75 (Note 6, 7)	5.5	-	-	-	1.65	-	-	V
			50 (Note 6, 7)	5.5	-	-	-	-	-	1.65	V
Input Leakage Current	II	V _{CC} or GND	-	5.5	-	±0.1	-	±1	-	±1	μА
Quiescent Supply Current MSI	I _{CC}	V _{CC} or GND	0	5.5	-	8	-	80	-	160	μΑ
ACT TYPES											
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage	V _{OH}	V _{IH} or V _{IL}	-0.05	4.5	4.4	-	4.4	-	4.4	-	V
			-24	4.5	3.94	-	3.8	-	3.7	-	V
			-75 (Note 6, 7)	5.5	ı	-	3.85	-	-	-	V
			-50 (Note 6, 7)	5.5	-	-	-	-	3.85	-	V
Low Level Output Voltage	V_{OL}	V _{IH} or V _{IL}	0.05	4.5	-	0.1	-	0.1	-	0.1	V
			24	4.5	-	0.36	-	0.44	-	0.5	V
			75 (Note 6, 7)	5.5	-	-	-	1.65	-	-	V
			50 (Note 6, 7)	5.5	-	-	-	-	-	1.65	V
Input Leakage Current	II.	V _{CC} or GND	-	5.5	-	±0.1	-	±1	-	±1	μА
Quiescent Supply Current MSI	I _{CC}	V _{CC} or GND	0	5.5	-	8	-	80	-	160	μА
Additional Supply Current per Input Pin TTL Inputs High 1 Unit Load	Δl _{CC}	V _{CC} -2.1	-	4.5 to 5.5	-	2.4	-	2.8	-	3	mA

NOTES:

- 6. Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.
- 7. Test verifies a minimum 50Ω transmission-line-drive capability at $85^{0}C,75\Omega$ at $125^{0}C.$

ACT Input Load Table

INPUT	UNIT LOAD
S0, S1, nl0, nl1	1
nE	0.47

NOTE: Unit load is ΔI_{CC} limit specified in DC Electrical Specifications Table, e.g., 2.4mA max at 25°C.

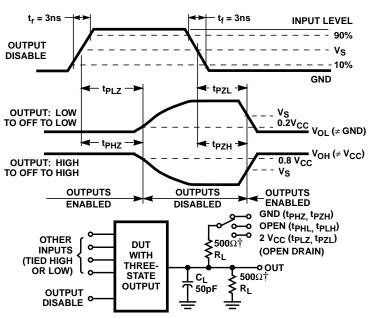
Switching Specifications Input t_r , t_f = 3ns, C_L = 50pF (Worst Case)

			-40 ^c	C TO 85°	С	-55	°C TO 12	5°C	
PARAMETER	SYMBOL	V _{CC} (V)	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
AC TYPES									
Propagation Delay, S0, S1, to Y	t _{PLH} , t _{PHL}	1.5	-	-	227	-	-	250	ns
		3.3 (Note 9)	7.2	-	25.5	7	-	28	ns
		5 (Note 10)	5.2	-	18.2	5	-	20	ns
Propagation Delay, nI to Y	t _{PLH} , t _{PHL}	1.5	-	-	151	-	-	166	ns
		3.3	4.8	-	16.9	4.7	-	18.6	ns
		5	3.4	-	12.1	3.3	-	13.3	ns
Propagation Delay, nE to Y	t _{PLH} , t _{PHL}	1.5	-	-	134	-	-	148	ns
		3.3	4.3	-	15	4.1	-	16.5	ns
		5	3.1	-	10.7	3	-	11.8	ns
Input Capacitance	Cl	-	-	-	10	-	-	10	pF
Power Dissipation Capacitance	C _{PD} (Note 11)	-	-	93	-	-	93	-	pF
ACT TYPES				•			•	•	
Propagation Delay, S0, S1, to Y	t _{PLH} , t _{PHL}	5 (Note 10)	5.7	-	20	5.5	-	22	ns
Propagation Delay, nI to Y	t _{PLH} , t _{PHL}	5	4.6	-	16.4	4.5	-	18	ns
Propagation Delay, nE to Y	t _{PLH} , t _{PHL}	5	3.2	-	11.5	3.2	-	12.6	ns
Input Capacitance	Cl	-	-	-	10	-	-	10	pF
Power Dissipation Capacitance	C _{PD} (Note 11)	-	-	93	-	-	93	-	pF

NOTES:

- 8. Limits tested at 100%.
- 9. 3.3V Min at 3.6V, Max at 3V.
- 10. 5V Min at 5.5V, Max at 4.5V.

11. C_{PD} is used to determine the dynamic power consumption per multiplexer. AC: $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ ACT: $P_D = V_{CC}^2 f_i (C_{PD} + C_L) + V_{CC} \Delta I_{CC}$ where f_i = input frequency, C_L = output load capacitance, V_{CC} = supply voltage.



†FOR AC SERIES ONLY: WHEN V $_{\text{CC}}$ = 1.5V, R_{L} = 1k Ω

FIGURE 1. THREE-STATE PROPAGATION DELAY WAVEFORMS AND TEST CIRCUIT

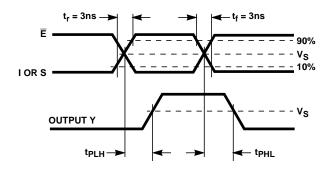
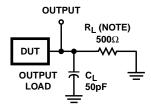


FIGURE 2. PROPAGATION DELAY TIMES AND TEST CIRCUIT



NOTE: For AC Series Only: When V_{CC} = 1.5V, R_L = 1k Ω .

	CD74AC	CD74ACT
Input Level	V _{CC}	3V
Input Switching Voltage, V _S	0.5 V _{CC}	1.5V
Output Switching Voltage, V _S	0.5 V _{CC}	0.5 V _{CC}

FIGURE 3. PROPAGATION DELAY TIMES

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